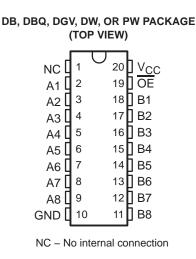
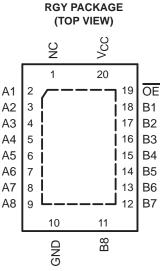
#### SN74CBT3245C 8-BIT FET BUS SWITCH 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION SCDS131A – SEPTEMBER 2003 – REVISED OCTOBER 2003

- Undershoot Protection for Off-Isolation on A and B Ports Up To -2 V
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance (r<sub>on</sub>) Characteristics (r<sub>on</sub> = 3 Ω Typical)
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion (C<sub>io(OFF)</sub> = 5.5 pF Typical)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I<sub>CC</sub> = 3 µA Max)
- V<sub>CC</sub> Operating Range From 4 V to 5.5 V
- Data I/Os Support 0 to 5-V Signaling Levels (0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, 5-V)



- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22

   2000-V Human-Body Model (A114-B, Class II)
   1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: USB Interface, Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating



NC – No internal connection

#### description/ordering information

The SN74CBT3245C is a high-speed TTL-compatible FET bus switch with low ON-state resistance ( $r_{on}$ ), allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBT3245C provides protection for undershoot up to -2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBT3245C is organized as an 8-bit bus switch with a single output-enable ( $\overline{OE}$ ) input. When  $\overline{OE}$  is low, the bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When  $\overline{OE}$  is high, the bus switch is OFF, and the high-impedance state exists between the A and B ports.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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### **SN74CBT3245C** 8-BIT FET BUS SWITCH 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

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#### description/ordering information (continued)

This device is fully specified for partial-power-down applications using Ioff. The Ioff feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, OE should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Τ <sub>Α</sub>	PACKAGI	Eţ	ORDERABLE PART NUMBER	TOP-SIDE MARKING							
	QFN – RGY	Tape and reel	SN74CBT3245CRGYR	CU245C							
		Tube	SN74CBT3245CDW	00700450							
	SOIC – DW	Tape and reel	SN74CBT3245CDWR	CBT3245C							
		Tube	SN74CBT3245CDB	0110450							
$-40^{\circ}C$ to $85^{\circ}C$	SSOP – DB	Tape and reel	SN74CBT3245CDBR	CU245C							
	SSOP (QSOP) – DBQ	Tape and reel	SN74CBT3245CDBQR	CBT3245C							
		Tube	SN74CBT3245CPW	0110450							
	TSSOP – PW	Tape and reel	SN74CBT3245CPWR	CU245C							
	TVSOP – DGV	Tape and reel	SN74CBT3245CDGVR	CU245C							

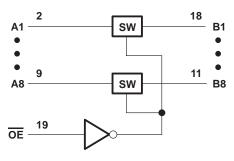
#### ORDERING INFORMATION

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

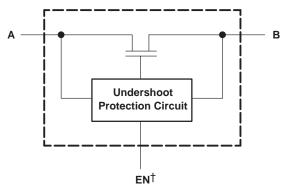
	INPUT/OUTPUT A	FUNCTION		
L	В	A port = B port		
Н	Z	Disconnect		

#### logic diagram (positive logic)





#### simplified schematic, each FET switch (SW)



<sup>†</sup> EN is the internal enable signal applied to the switch.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

$\begin{array}{llllllllllllllllllllllllllllllllllll$	7 V 7 V mA mA mA MA C/W C/W C/W C/W
(see Note 6): RGY package	:/W

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground unless otherwise specified.
  - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 3. VI and VO are used to denote specific conditions for  $V_{I/O}$ .
  - 4. II and IO are used to denote specific conditions for II/O.
  - 5. The package thermal impedance is calculated in accordance with JESD 51-7.
  - 6. The package thermal impedance is calculated in accordance with JESD 51-5.

#### recommended operating conditions (see Note 7)

		MIN	MAX	UNIT
VCC	Supply voltage	4	5.5	V
VIH	High-level control input voltage	2	5.5	V
VIL	Low-level control input voltage	0	0.8	V
V <sub>I/O</sub>	Data input/output voltage	0	5.5	V
Τ <sub>Α</sub>	Operating free-air temperature	-40	85	°C

NOTE 7: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



### SN74CBT3245C 8-BIT FET BUS SWITCH 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER		TEST CONDITIC	NS	MIN TYP <sup>†</sup>	MAX	UNIT
VIK	Control inputs	V <sub>CC</sub> = 4.5 V,	I <sub>IN</sub> = -18 mA			-1.8	V
VIKU	Data inputs	V <sub>CC</sub> = 5 V,	0 mA > I <sub>I</sub> $\ge$ -50 mA, V <sub>IN</sub> = V <sub>CC</sub> or GND,	Switch OFF		-2	V
I <sub>IN</sub>	Control inputs	V <sub>CC</sub> = 5.5 V,	$V_{IN} = V_{CC} \text{ or } GND$			±1	μΑ
IOZ‡		V <sub>CC</sub> = 5.5 V,	$V_{O} = 0$ to 5.5 V, $V_{I} = 0$ ,	Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND		±10	μA
loff		$V_{CC} = 0,$	$V_{O} = 0$ to 5.5 V,	$V_{\parallel} = 0$		10	μΑ
ICC		V <sub>CC</sub> = 5.5 V,	I <sub>I/O</sub> = 0, V <sub>IN</sub> = V <sub>CC</sub> or GND,	Switch ON or OFF		3	μΑ
∆ICC§	Control inputs	V <sub>CC</sub> = 5.5 V,	One input at 3.4 V,	Other inputs at $V_{CC}$ or GND		2.5	mA
C <sub>in</sub>	Control inputs	V <sub>IN</sub> = 3 V or 0			4		pF
Cio(OFF	=)	V <sub>I/O</sub> = 3 V or 0,	Switch OFF,	$V_{IN} = V_{CC}$ or GND	5.5		pF
Cio(ON)	)	V <sub>I/O</sub> = 3 V or 0,	Switch ON,	$V_{IN} = V_{CC}$ or GND	14		pF
		$V_{CC} = 4 V$ , TYP at $V_{CC} = 4 V$	V <sub>1</sub> = 2.4 V,	I <sub>O</sub> = -15 mA	8	12	
ron¶				I <sub>O</sub> = 64 mA	3	6	Ω
-		$V_{CC} = 4.5 V$	$V_{I} = 0$	I <sub>O</sub> = 30 mA	3	6	]
			V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA	5	10	

 $V_{IN}$  and  $I_{IN}$  refer to control inputs.  $V_I$ ,  $V_O$ ,  $I_I$ , and  $I_O$  refer to data pins.

<sup>†</sup> All typical values are at  $V_{CC}$  = 5 V (unless otherwise noted),  $T_A$  = 25°C.

<sup>‡</sup> For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

This is the increase in supply current for each input that is at the specified voltage level, rather than V<sub>CC</sub> or GND.

¶ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO	V <sub>CC</sub> = 4 V	= V <sub>CC</sub> ± 0.	= 5 V 5 V	UNIT
	(INFOT)	(OUTPUT)	MIN MAX	MIN	MAX	
<sup>t</sup> pd <sup>#</sup>	A or B	B or A	0.24		0.15	ns
ten	OE	A or B	5.1	1.5	4.7	ns
<sup>t</sup> dis	OE	A or B	4.9	1.5	5.3	ns

<sup>#</sup> The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



### **SN74CBT3245C 8-BIT FET BUS SWITCH** 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

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#### undershoot characteristics (see Figures 1 and 2)

	 ONDITIONS	MIN	TYPŤ	MAX	UNIT
νουτυ νοα	F, $V_{IN} = V_{CC}$ or GND	2	V <sub>OH</sub> -0.3		V

<sup>†</sup> All typical values are at  $V_{CC}$  = 5 V (unless otherwise noted),  $T_A$  = 25°C.

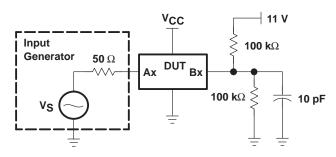


Figure 1. Device Test Setup

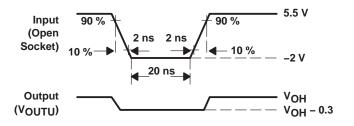
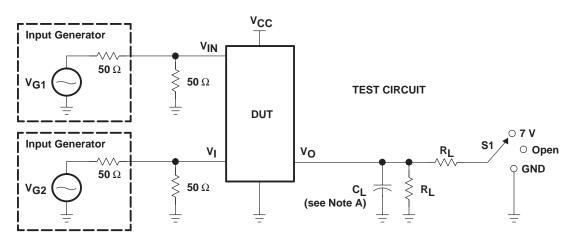


Figure 2. Transient Input Voltage (V<sub>I</sub>) and Output Voltage (V<sub>OUTU</sub>) Waveforms (Switch OFF)



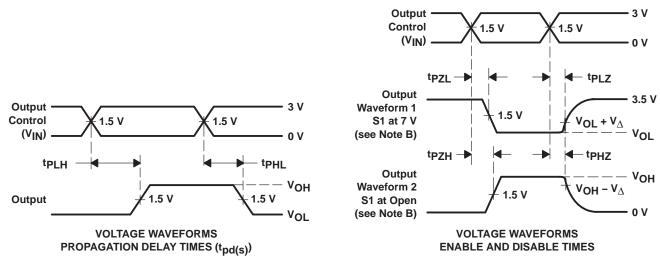
### SN74CBT3245C 8-BIT FET BUS SWITCH 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

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#### PARAMETER MEASUREMENT INFORMATION

TEST	VCC	S1	RL	VI	сL	$v_\Delta$
<sup>t</sup> pd(s)	$\begin{array}{c} 5 \text{ V} \pm 0.5 \text{ V} \\ 4 \text{ V} \end{array}$	Open Open	<b>500</b> Ω <b>500</b> Ω	V <sub>CC</sub> or GND V <sub>CC</sub> or GND	50 pF 50 pF	
tPLZ/tPZL	$\begin{array}{c} 5 \text{ V} \pm 0.5 \text{ V} \\ 4 \text{ V} \end{array}$	7 V 7 V	<b>500</b> Ω <b>500</b> Ω	GND GND	50 pF 50 pF	0.3 V 0.3 V
<sup>t</sup> PHZ <sup>/t</sup> PZH	$\begin{array}{c} 5 \text{ V} \pm 0.5 \text{ V} \\ 4 \text{ V} \end{array}$	Open Open	<b>500</b> Ω <b>500</b> Ω	VCC VCC	50 pF 50 pF	0.3 V 0.3 V



#### NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. tPZL and tPZH are the same as ten.
- G. tpLH and tpHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.







### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	. ,						(6)			× ,	
SN74CBT3245CDBQR	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CBT3245C	Samples
SN74CBT3245CDBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CU245C	Samples
SN74CBT3245CDGVR	ACTIVE	TVSOP	DGV	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CU245C	Samples
SN74CBT3245CDW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT3245C	Samples
SN74CBT3245CDWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT3245C	Samples
SN74CBT3245CPW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CU245C	Samples
SN74CBT3245CPWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CU245C	Samples
SN74CBT3245CRGYR	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CU245C	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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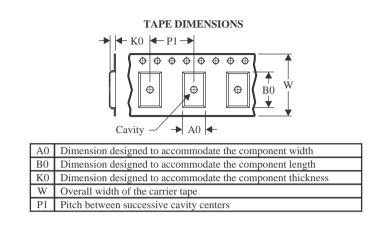


Texas

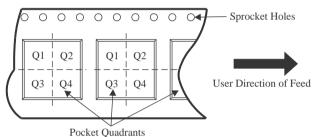
STRUMENTS

#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



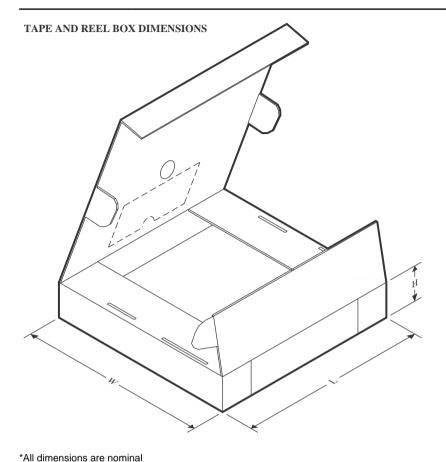
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CBT3245CDBQR	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74CBT3245CDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74CBT3245CDGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74CBT3245CDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74CBT3245CPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74CBT3245CRGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1



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## PACKAGE MATERIALS INFORMATION

3-Jun-2022



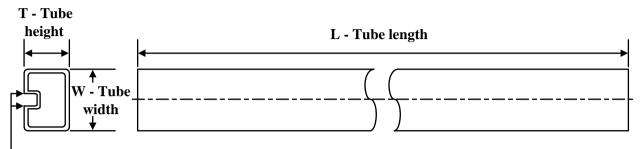
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)				
SN74CBT3245CDBQR	SSOP	DBQ	20	2500	356.0	356.0	35.0				
SN74CBT3245CDBR	SSOP	DB	20	2000	356.0	356.0	35.0				
SN74CBT3245CDGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0				
SN74CBT3245CDWR	SOIC	DW	20	2000	367.0	367.0	45.0				
SN74CBT3245CPWR	TSSOP	PW	20	2000	367.0	367.0	38.0				
SN74CBT3245CRGYR	VQFN	RGY	20	3000	367.0	367.0	35.0				

#### TEXAS INSTRUMENTS

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#### TUBE



#### - B - Alignment groove width

\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74CBT3245CDW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74CBT3245CPW	PW	TSSOP	20	70	530	10.2	3600	3.5

## **PW0020A**



## **PACKAGE OUTLINE**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



## PW0020A

## **EXAMPLE BOARD LAYOUT**

#### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## PW0020A

## **EXAMPLE STENCIL DESIGN**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DBQ (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AD.



## **DB0020A**



## **PACKAGE OUTLINE**

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



## DB0020A

## **EXAMPLE BOARD LAYOUT**

### SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## DB0020A

## **EXAMPLE STENCIL DESIGN**

### SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

#### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



### **GENERIC PACKAGE VIEW**

#### VQFN - 1 mm max height

PLASTIC QUAD FGLATPACK - NO LEAD

3.5 x 4.5, 0.5 mm pitch

**RGY 20** 

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





4225264/A

## **RGY0020A**



## **PACKAGE OUTLINE**

#### VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



## **RGY0020A**

## **EXAMPLE BOARD LAYOUT**

#### VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



## **RGY0020A**

## **EXAMPLE STENCIL DESIGN**

### VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



## **DW0020A**



## **PACKAGE OUTLINE**

#### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



## DW0020A

## **EXAMPLE BOARD LAYOUT**

#### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## DW0020A

## **EXAMPLE STENCIL DESIGN**

#### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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